NSN 5962-01-214-2151

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Body Length:	
0.960 inches	
Body Width:	
Between 0.220 ir	iches and 0.310 inches
Body Height:	
0.185 inches	
Maximum Powe	r Dissipation Rating:
794.0 milliwatts	
Operating Temp	purature Range:
-55.0/+125.0 deg	rees celsius
Storage Tempu	rature Range:
-65.0/+150.0 deg	rees celsius
Features Provid	ed:
Hermetically sea	ed and burn in and programmable and schottky and 3-state output
Inclosure Mater	al:
Ceramic	
Inclosure Config	guration:
Dual-in-line	
Output Logic Fo	orm:
Transistor-transis	stor logic
Input Circuit Pa	ttern:
12 input	
Case Outline So	purce And Designator:
D-6 mil-m-38510	
Terminal Surfac	e Treatment:
Solder	
Voltage Rating	And Type Per Characteristic:
7.0 volts power	source
Time Rating Per	Chacteristic:
85.00 nanosecor	ds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	Туре:
Rom	
Memory Capaci	ty:
Unknown	
Test Data Docu	nent:
96906-mil-std-88	3 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type A	And Quantity:
18 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure	

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Demilitarization:

Yes - demil/mli

Fiig:

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